

MAXIM

1.25 Ω , Dual SPST, CMOS Analog Switches

General Description

The MAX4680/MAX4690/MAX4700 dual analog switches feature low on-resistance of 1.25 Ω max. On-resistance is matched between switches to 0.3 Ω max and is flat (0.3 Ω max) over the specified signal range. Each switch can handle Rail-to-Rail[®] analog signals. Off-leakage current is only 5nA max at +85°C. These analog switches are ideal in low-distortion applications and are the preferred solution over mechanical relays in automatic test equipment or applications where current switching is required. They have low power requirements, require less board space, and are more reliable than mechanical relays.

The MAX4680 has two NC (normally closed) switches, and the MAX4690 has two NO (normally open) switches. The MAX4700 has one NC and one NO switch and features guaranteed break-before-make switching.

These devices operate from a +4.5V to +36V single supply or from $\pm 4.5V$ to $\pm 20V$ dual supplies. A separate logic supply pin guarantees TTL/CMOS-logic compatibility while operating across the entire supply voltage range.

Applications

Reed Relay Replacement Data Acquisition Systems
Test Equipment Sample-and-Hold Circuits
Communication Systems
PBX, PABX Systems

Features

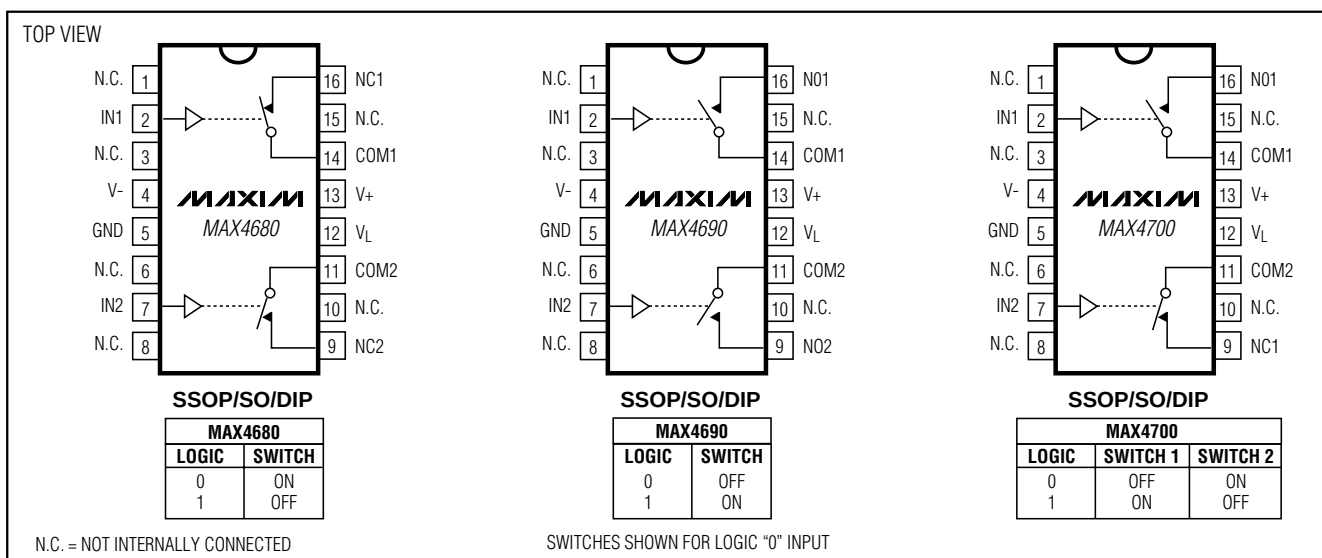
- ♦ Low On-Resistance (1.25 Ω max)
- ♦ Guaranteed R_{ON} Match Between Channels (0.3 Ω max)
- ♦ Guaranteed R_{ON} Flatness Over Specified Signal Range (0.3 Ω max)
- ♦ Rail-to-Rail Signal Handling
- ♦ Guaranteed Break-Before-Make (MAX4700)
- ♦ +4.5V to +36V Single-Supply Operation
 $\pm 4.5V$ to $\pm 20V$ Dual-Supply Operation
- ♦ TTL/CMOS-Compatible Control Inputs
- ♦ >2kV ESD Protection per Method 3015.7

Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX4680CAE	0°C to +70°C	16 SSOP
MAX4680CWE	0°C to +70°C	16 Wide SO
MAX4680CPE	0°C to +70°C	16 Plastic DIP
MAX4680EAE	-40°C to +85°C	16 SSOP
MAX4680EWE	-40°C to +85°C	16 Wide SO
MAX4680EPE	-40°C to +85°C	16 Plastic DIP

Ordering Information continued at end of data sheet.

Pin Configurations/Functional Diagrams/Truth Tables



Rail-to-Rail is a registered trademark of Nippon Motorola, Ltd.

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MAX4680/MAX4690/MAX4700

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ABSOLUTE MAXIMUM RATINGS

V+ to GND -0.3V to +44V
 V- to GND +0.3V to -44V
 V+ to V- -0.3V to +44V
 VL to GND -0.3V to (V+ + 0.3V)
 All Other Pins to GND (Note 1) (V- - 0.3V) to (V+ + 0.3V)
 Continuous Current (COM_, NO_, NC_) ± 200 mA
 Peak Current (COM_, NO_, NC_)
 (pulsed at 1ms, 10% duty cycle) ± 300 mA

Continuous Power Dissipation ($T_A = +70^\circ\text{C}$)
 SSOP (derate 7.1mW/ $^\circ\text{C}$ above $+70^\circ\text{C}$) 571mW
 Wide SO (derate 9.52mW/ $^\circ\text{C}$ above $+70^\circ\text{C}$) 762mW
 Plastic DIP (derate 10.53mW/ $^\circ\text{C}$ above $+70^\circ\text{C}$) 842mW
 Operating Temperature Ranges
 MAX4_0C_E 0°C to $+70^\circ\text{C}$
 MAX4_0E_E -40°C to $+85^\circ\text{C}$
 Storage Temperature Range -65°C to $+150^\circ\text{C}$
 Lead Temperature (soldering, 10sec) $+300^\circ\text{C}$

Note 1: Signals on NC_, NO_, COM_, or IN_ exceeding V+ or V- are clamped by internal diodes. Limit forward diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = +15V, V- = -15V, VL = +5V, VIN_H = +2.4V, VIN_L = +0.8V, $T_A = T_{\text{MIN}}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25^\circ\text{C}$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Input Voltage Range (Note 3)	$V_{\text{COM}_-}, V_{\text{NO}_-}, V_{\text{NC}_-}$			V-		V+	V
COM_ to NO_ or NC_ On-Resistance	R_{ON}	$I_{\text{COM}_-} = 10\text{mA}, V_{\text{NO}_-} \text{ or } V_{\text{NC}_-} = \pm 10\text{V},$	$T_{\text{A}} = +25^{\circ}\text{C}$	0.9	1.25		Ω
			$T_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}$		1.5		
COM_ to NO_ or NC_ On-Resistance Match Between Channels (Notes 3, 4)	ΔR_{ON}	$I_{\text{COM}_-} = 10\text{mA}, V_{\text{NO}_-} \text{ or } V_{\text{NC}_-} = \pm 10\text{V}$	$T_{\text{A}} = +25^{\circ}\text{C}$	0.09	0.3		Ω
			$T_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}$		0.5		
COM_ to NO_ or NC_ On-Resistance Flatness (Notes 3, 5)	$R_{\text{FLAT(ON)}}$	$I_{\text{COM}_-} = 10\text{mA}; V_{\text{NO}_-} \text{ or } V_{\text{NC}_-} = -5\text{V}, 0, 5\text{V}$	$T_{\text{A}} = +25^{\circ}\text{C}$	0.06	0.3		Ω
			$T_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}$		0.5		
Off-Leakage Current (NO_ or NC_) (Note 6)	$I_{\text{NO}_-}, I_{\text{NC}_-}$	$V_{\text{COM}_-} = \pm 10\text{V}, V_{\text{NO}_-} \text{ or } V_{\text{NC}_-} = \mp 10\text{V}$	$T_{\text{A}} = +25^{\circ}\text{C}$	-0.5	0.01	0.5	nA
			$T_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}$	-5		5	
COM_ Off-Leakage Current (Note 6)	$I_{\text{COM}_-}(\text{OFF})$	$V_{\text{COM}_-} = \pm 10\text{V}, V_{\text{NO}_-} \text{ or } V_{\text{NC}_-} = \mp 10\text{V}$	$T_{\text{A}} = +25^{\circ}\text{C}$	-0.5	0.01	0.5	nA
			$T_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}$	-2.5		2.5	
COM_ On-Leakage Current (Note 6)	$I_{\text{COM}_-}(\text{ON})$	$V_{\text{COM}_-} = \pm 10\text{V}, V_{\text{NO}_-} \text{ or } V_{\text{NC}_-} = \pm 10\text{V}$ or floating	$T_{\text{A}} = +25^{\circ}\text{C}$	-1	0.01	1	nA
			$T_{\text{A}} = T_{\text{MIN}} \text{ to } T_{\text{MAX}}$	-20		20	
LOGIC INPUT							
Input Current with Input Voltage High	I_{IN_H}	$\text{IN}_- = 2.4\text{V}, \text{ all others} = 0.8\text{V}$		-0.5	0.001	0.5	μA
Input Current with Input Voltage Low	I_{IN_L}	$\text{IN}_- = 0.8\text{V}, \text{ all others} = 2.4\text{V}$		-0.5	0.001	0.5	

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ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

(V₊ = +15V, V₋ = -15V, V_L = +5V, V_{IN_H} = +2.4V, V_{IN_L} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Logic Input Voltage High	V _{IN_H}			2.4			V
Logic Input Voltage Low	V _{IN_L}					0.8	V
POWER SUPPLY							
Power-Supply Range				±4.5		±20.0	V
Positive Supply Current	I ₊	V _{IN_} = 0 or 5V	T _A = +25°C	-0.5	0.01	0.5	μA
			T _A = T _{MIN} to T _{MAX}	-5		5	
Negative Supply Current	I ₋	V _{IN_} = 0 or 5V	T _A = +25°C	-0.5	0.01	0.5	μA
			T _A = T _{MIN} to T _{MAX}	-5		5	
Logic Supply Current	I _L	V _{IN_} = 0 or 5V	T _A = +25°C	-0.5	0.01	0.5	μA
			T _A = T _{MIN} to T _{MAX}	-5		5	
Ground Current	I _{GND}	V _{IN_} = 0 or 5V	T _A = +25°C	-0.5	0.01	0.5	μA
			T _A = T _{MIN} to T _{MAX}	-5		5	
SWITCH DYNAMIC CHARACTERISTICS							
Turn-On Time	t _{ON}	V _{COM_} = ±10V, Figure 2	T _A = +25°C	130		275	ns
			T _A = T _{MIN} to T _{MAX}			400	
Turn-Off Time	t _{OFF}	V _{COM_} = ±10V, Figure 2	T _A = +25°C	90		175	ns
			T _A = T _{MIN} to T _{MAX}			300	
Break-Before-Make Time (MAX4700 only)	t _{OPEN}	V _{COM_} = ±10V, Figure 3, T _A = +25°C		5	30		ns
Charge Injection	Q	C _L = 1.0nF, V _{GEN} = 0, R _{GEN} = 0, Figure 4			550		pC
Off-Isolation (Note 7)	V _{ISO}	R _L = 50Ω, C _L = 5pF, f = 1MHz, Figure 5			-53		dB
Crosstalk (Note 8)	V _{CT}	R _L = 50Ω, C _L = 5pF, f = 1MHz, Figure 6			-65		dB
NC_ or NO_ Capacitance	C _{OFF}	f = 1MHz, Figure 7			115		pF
COM Off-Capacitance	C _{COM}	f = 1MHz, Figure 7			115		pF
On-Capacitance	C _{COM}	f = 1MHz, Figure 8			520		pF

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ELECTRICAL CHARACTERISTICS—Single Supply

(V₊ = +12V, V₋ = 0, V_L = +5V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Input Voltage Range (Note 3)	V _{COM_} , V _{NO_} , V _{NC_}			GND		V+	V
COM_ to NO_ or NC_ On-Resistance	R _{ON}	I _{COM_} = 10mA, V _{NO_} or V _{NC_} = 10V	T _A = +25°C	1.6	3		Ω
			T _A = T _{MIN} to T _{MAX}	3.5			
COM_ to NO_ or NC_ On-Resistance Match Between Channels (Notes 3, 4)	ΔR _{ON}	I _{COM_} = 10mA, V _{NO_} or V _{NC_} = 10V	T _A = +25°C	0.1	0.4		Ω
			T _A = T _{MIN} to T _{MAX}	0.5			
COM_ to NO_ or NC_ On-Resistance Flatness (Notes 3, 5)	R _{FLAT(ON)}	I _{COM_} = 10mA; V _{NO_} or V _{NC_} = 3V, 6V, 9V	T _A = +25°C	0.2	0.4		Ω
			T _A = T _{MIN} to T _{MAX}	0.5			
Off-Leakage Current (NO_ or NC_) (Notes 6, 9)	I _{NO_} , I _{NC_}	V _{COM_} = 1V, 10V; V _{NO_} or V _{NC_} = 10V, 1V	T _A = +25°C	-0.5	0.01	0.5	nA
			T _A = T _{MIN} to T _{MAX}	-5	5		
COM_ Off-Leakage Current (Notes 6, 9)	I _{COM_(OFF)}	V _{NO_} or V _{NC_} = 10V, 1V; V _{COM_} = 1V, 10V	T _A = +25°C	-0.5	0.01	0.5	nA
			T _A = T _{MIN} to T _{MAX}	-5	5		
COM_ On-Leakage Current (Notes 6, 9)	I _{COM_(ON)}	V _{COM_} = 1V, 10V; V _{NO_} or V _{NC_} = 1V, 10V, or floating	T _A = +25°C	-1	0.02	1	nA
			T _A = T _{MIN} to T _{MAX}	-20	20		
LOGIC INPUT							
Input Current with Input Voltage High	I _{IN_H}	I _{N_} = 2.4V, all others = 0.8V		-0.5	0.001	0.5	μA
Input Current with Input Voltage Low	I _{IN_L}	I _{N_} = 0.8V, all others = 2.4V		-0.5	0.001	0.5	μA
Logic Input Voltage High	V _{IN_H}			2.4			V
Logic Input Voltage Low	V _{IN_L}					0.8	V
POWER SUPPLY							
Power-Supply Range				+4.5		+36.0	V
Positive Supply Current	I+	V _{IN_} = 0 or 5V	T _A = +25°C	-0.5	0.001	0.5	μA
			T _A = T _{MIN} to T _{MAX}	5	5		
Logic Supply Current	I _L	V _{IN_} = 0 or 5V	T _A = +25°C	-0.5	0.001	0.5	μA
			T _A = T _{MIN} to T _{MAX}	5	5		
Ground Current	I _{GND}	V _{IN_} = 0 or 5V	T _A = +25°C	-0.5	0.001	0.5	μA
			T _A = T _{MIN} to T _{MAX}	5	5		

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ELECTRICAL CHARACTERISTICS—Single Supply (continued)

($V_+ = +12V$, $V_- = 0$, $V_L = +5V$, $V_{IN_H} = 2.4V$, $V_{IN_L} = 0.8V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25^\circ C$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
SWITCH DYNAMIC CHARACTERISTICS						
Turn-On Time (Note 3)	t_{ON}	$V_{COM_} = 10V$, Figure 2	$T_A = +25^\circ C$		225	400
			$T_A = T_{MIN}$ to T_{MAX}		500	ns
Turn-Off Time (Note 3)	t_{OFF}	$V_{COM_} = 10V$, Figure 2	$T_A = +25^\circ C$		100	250
			$T_A = T_{MIN}$ to T_{MAX}		350	ns
Break-Before-Make Time (Note 3)	t_{OPEN}	$V_{COM_} = 10V$, Figure 3, $T_A = +25^\circ C$	5	125		ns
Charge Injection	Q	$C_L = 1.0nF$, $V_{GEN} = 0$, $R_{GEN} = 0$, Figure 4		-60		pC
Crosstalk (Note 8)	V_{CT}	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 6		-65		dB
NC_ or NO_ Capacitance	C_{OFF}	$f = 1MHz$, Figure 7		175		pF
COM Off-Capacitance	C_{COM}	$f = 1MHz$, Figure 7		175		pF
On-Capacitance	C_{COM}	$f = 1MHz$, Figure 8		275		pF

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

Note 3: Guaranteed by design.

Note 4: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$.

Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal range.

Note 6: Leakage parameters are 100% tested at maximum-rated hot temperature and guaranteed by correlation at $+25^\circ C$.

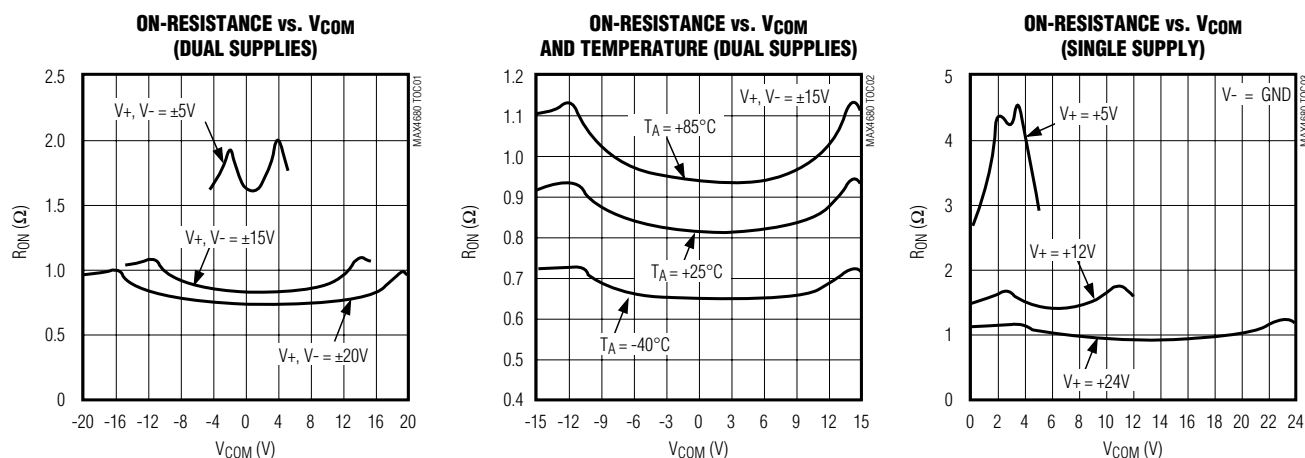
Note 7: Off-isolation = $20\log_{10} [V_{COM} / (V_{NC} \text{ or } V_{NO})]$, V_{COM} = output, V_{NC} or V_{NO} = input to off switch.

Note 8: Between any two switches.

Note 9: Leakage testing at single supply is guaranteed by testing with dual supplies.

Typical Operating Characteristics

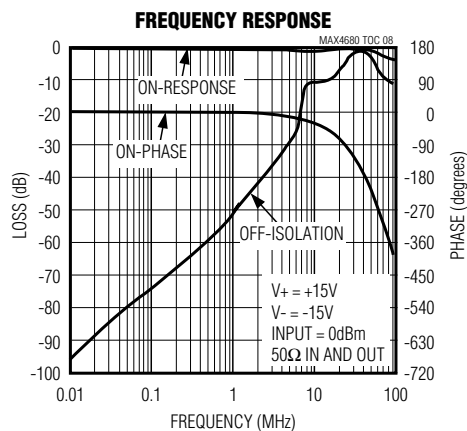
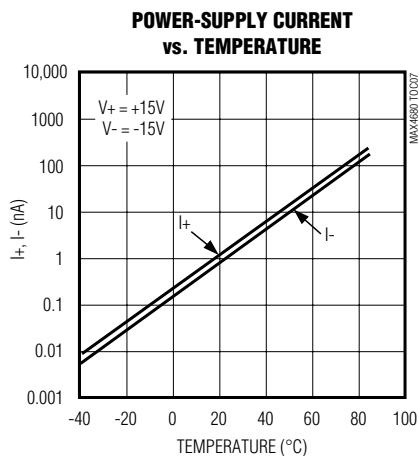
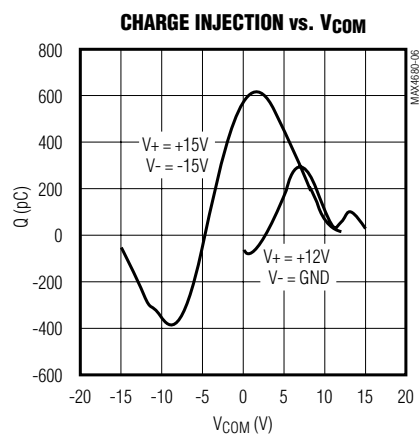
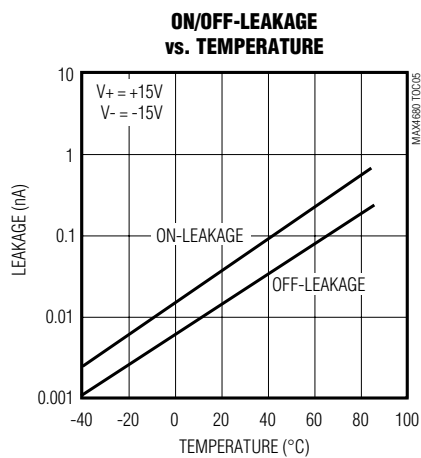
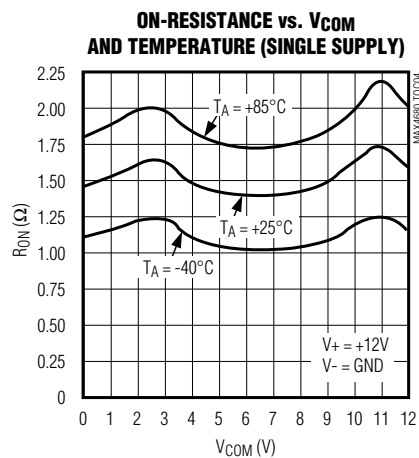
($T_A = +25^\circ C$, unless otherwise noted.)



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Typical Operating Characteristics (continued)

($T_A = +25^\circ\text{C}$, unless otherwise noted.)



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Pin Description

PIN			NAME	FUNCTION
MAX4680	MAX4690	MAX4700		
1, 3, 6, 8, 10, 15	1, 3, 6, 8, 10, 15	1, 3, 6, 8, 10, 15	N.C.	No connection. Not internally connected. Connect to GND or low-impedance point to improve on/off-isolation.
2, 7	2, 7	2, 7	IN1, IN2	Logic-Control Digital Inputs
4	4	4	V-	Negative Analog Supply Voltage Input. Connect to GND for single-supply operation.
5	5	5	GND	Ground
9, 16	–	–	NC2, NC1	Analog Switch Normally Closed Terminals
11, 14	11, 14	11, 14	COM2, COM1	Analog Switch Common Terminals
12	12	12	V _L	Logic Supply Input
13	13	13	V+	Positive Analog Supply Input
–	9, 16	–	NO2, NO1	Analog Switch Normally Open Terminals
–	–	9	NC1	Analog Switch Normally Closed Terminal
–	–	16	NO1	Analog Switch Normally Open Terminal

MAX4680/MAX4690/MAX4700

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Applications Information

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V_+ on first, then V_- , followed by the logic inputs, NO, or COM. If power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with the supply pins and a Schottky diode between V_+ and V_- for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to one diode drop below V_+ and one diode drop above V_- , but does not affect the devices' low switch resistance and low-leakage characteristics. Device operation is unchanged, and the difference between V_+ and V_- should not exceed 44V.

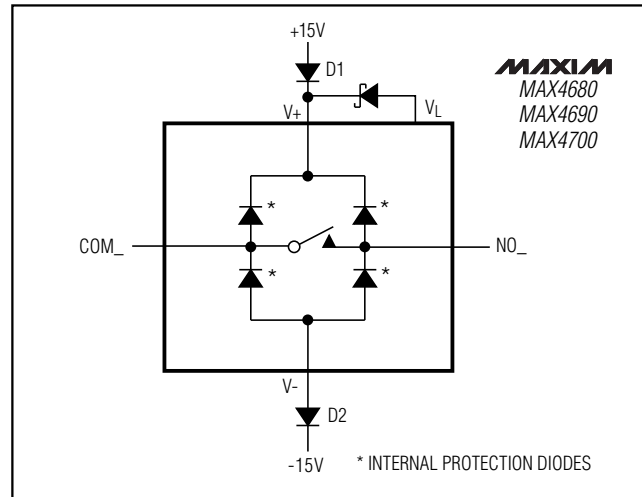


Figure 1. Overvoltage Protection Using External Blocking Diodes

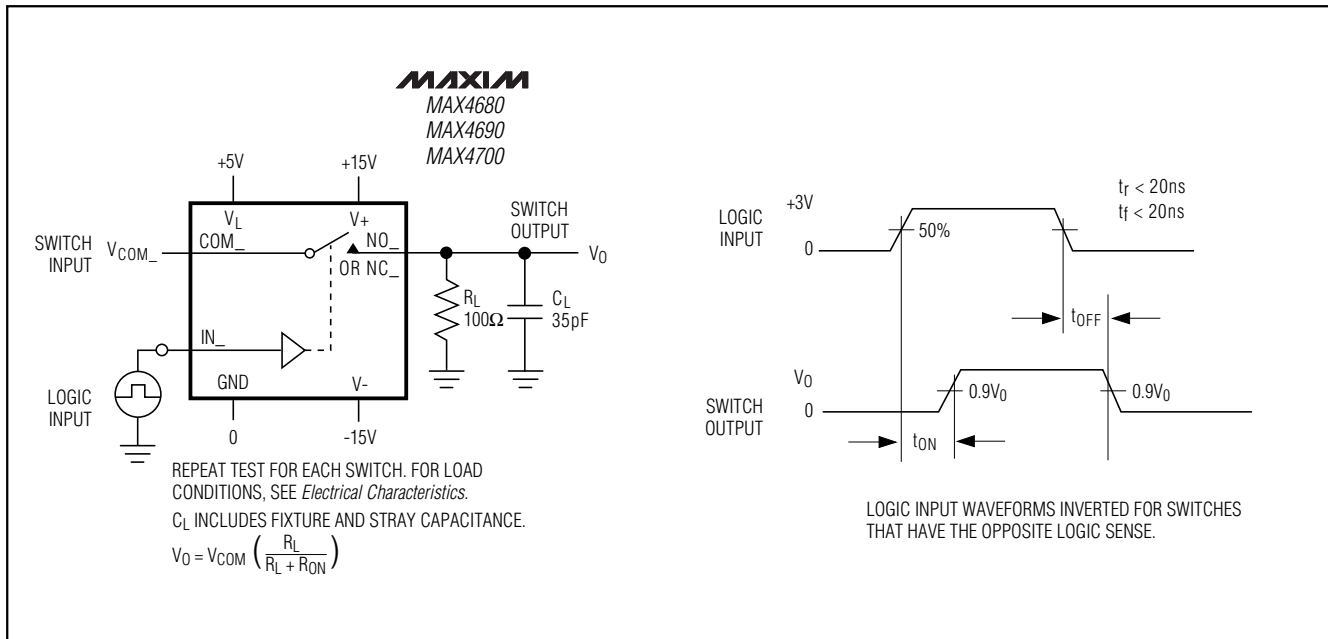
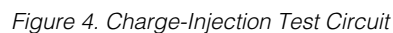


Figure 2. Switching-Time Test Circuit

MAX4680/MAX4690/MAX4700



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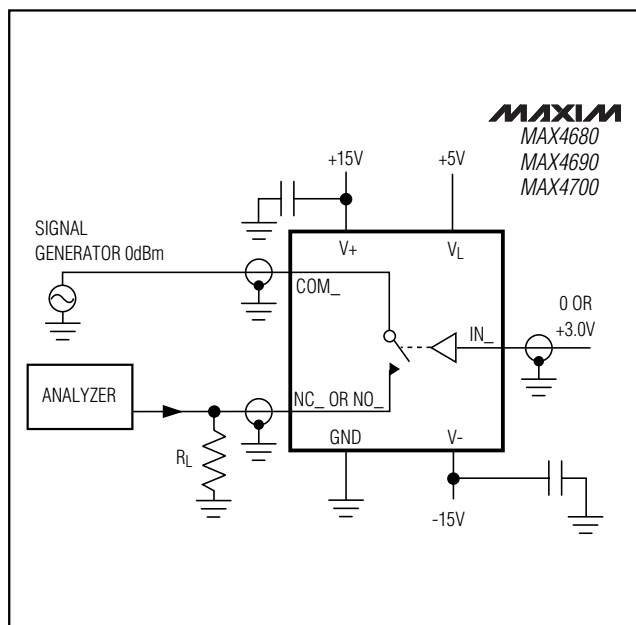


Figure 5. Off-Isolation Test Circuit

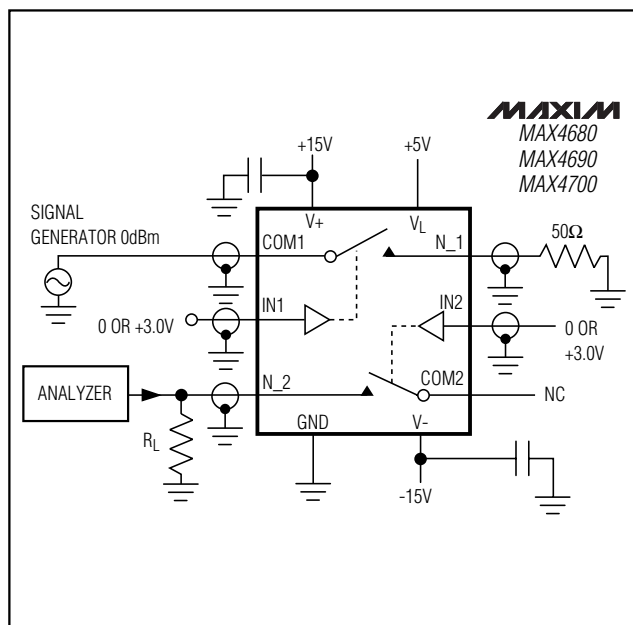


Figure 6. Crosstalk Test Circuit

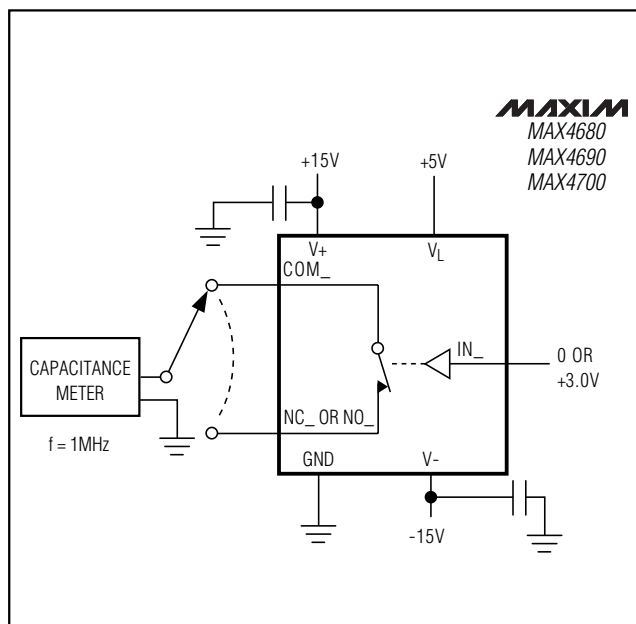


Figure 7. Switch Off-Capacitance Test Circuit

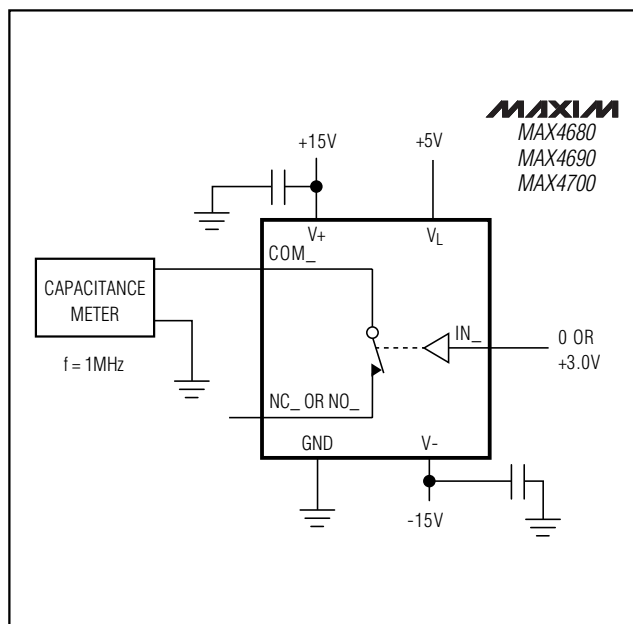


Figure 8. Switch On-Capacitance Test Circuit

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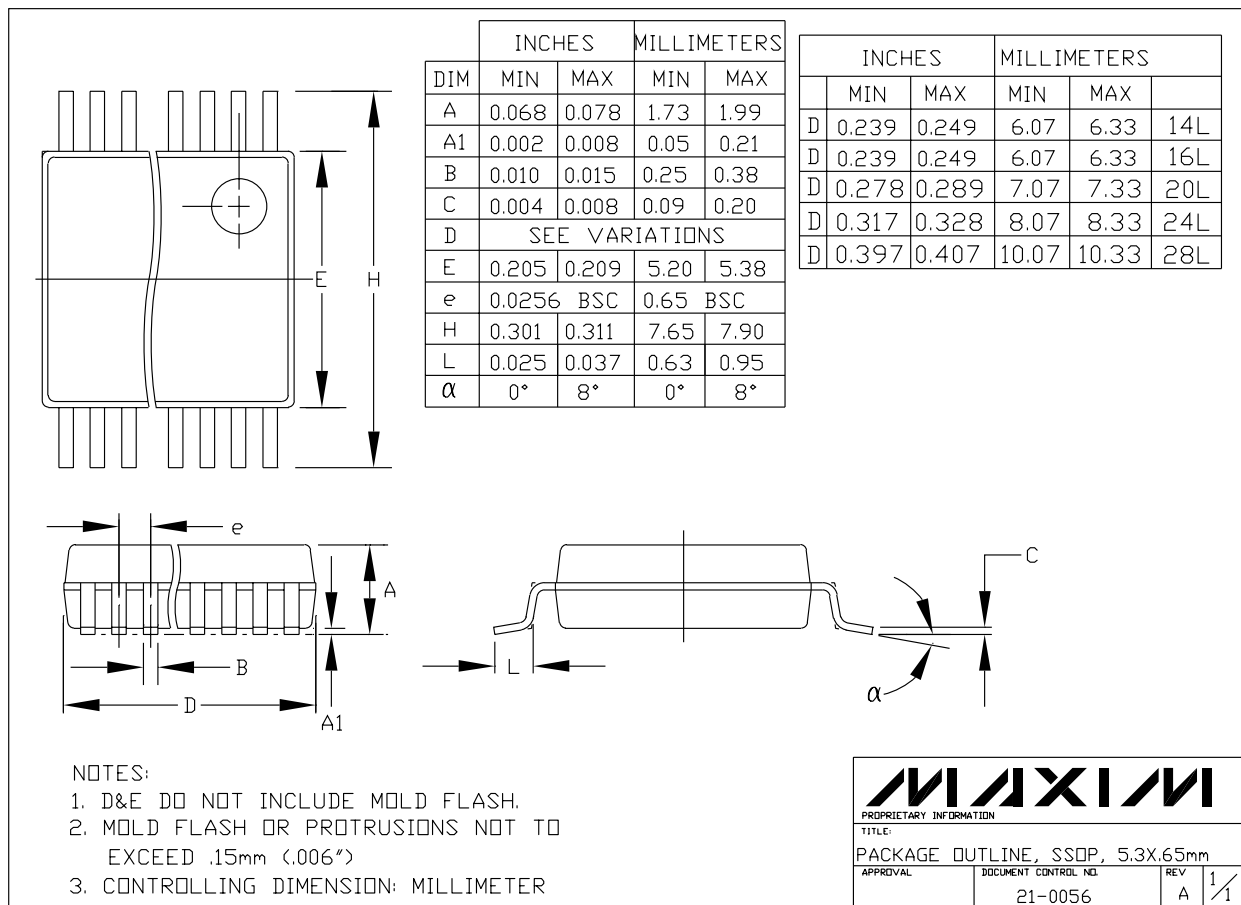
Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE
MAX4690CAE	0°C to +70°C	16 SSOP
MAX4690CWE	0°C to +70°C	16 Wide SO
MAX4690CPE	0°C to +70°C	16 Plastic DIP
MAX4690EAE	-40°C to +85°C	16 SSOP
MAX4690EWE	-40°C to +85°C	16 Wide SO
MAX4690EPE	-40°C to +85°C	16 Plastic DIP
MAX4700CAE	0°C to +70°C	16 SSOP
MAX4700CWE	0°C to +70°C	16 Wide SO
MAX4700CPE	0°C to +70°C	16 Plastic DIP
MAX4700EAE	-40°C to +85°C	16 SSOP
MAX4700EWE	-40°C to +85°C	16 Wide SO
MAX4700EPE	-40°C to +85°C	16 Plastic DIP

TRANSISTOR COUNT: 108

Chip Information

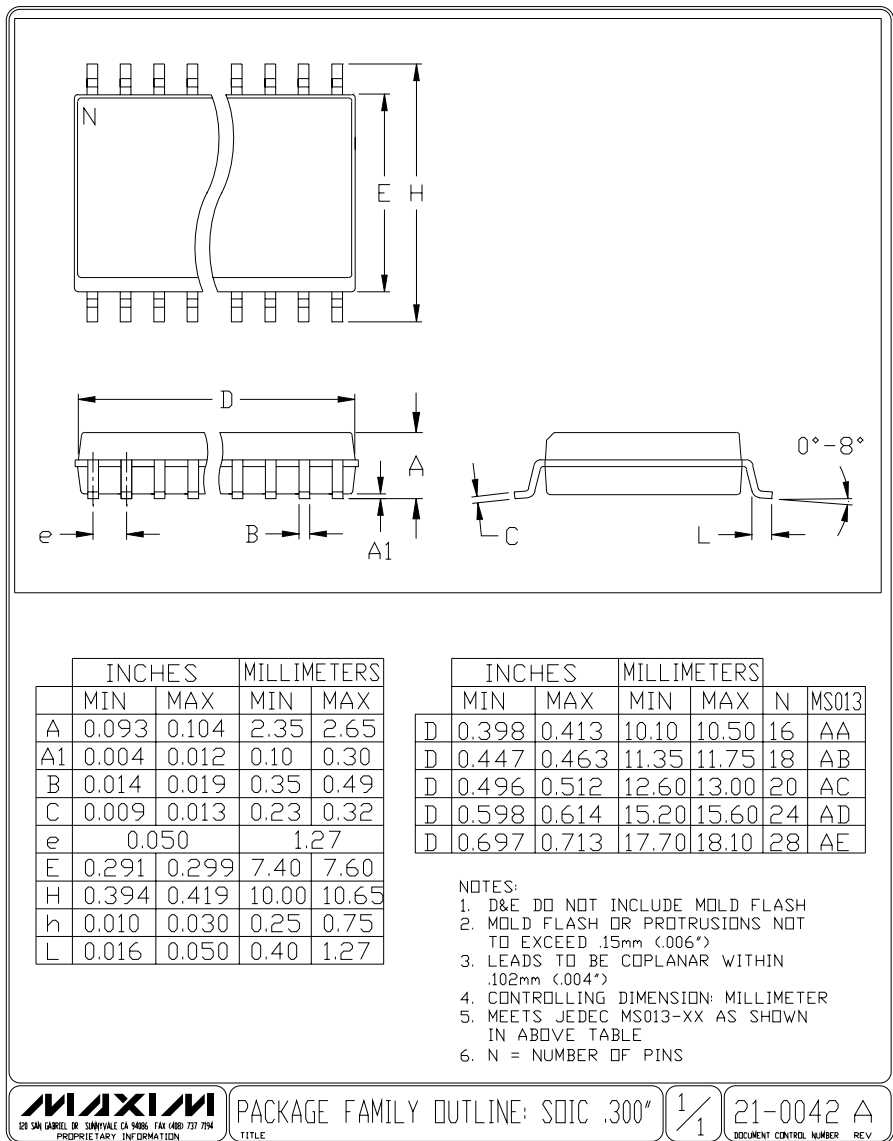
Package Information



MAX4680/MAX4690/MAX4700

1.25Ω, Dual SPST, CMOS Analog Switches

Package Information (continued)



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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